

<b>Specification</b>	<b>AXMW1030GYT-01</b>	Rev.: 3	Date: 2014-07-08
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**Oscillator type: Gated 1030 MHz Microwave Oscillator**

**For Secondary Radar Applications**

Parameter	min.	typ.	max.	Unit	Condition
<b>Nominal frequency</b>	1030.000			MHz	
<b>Frequency stability</b>					
Initial tolerance @ +25°C			±10	ppm	
vs. operating temperature range			±30	ppm	
operating temperature range	-40		+70	°C	
Long term (aging) per year			±5	ppm	
<b>RF output</b>					
Signal waveform	Sine wave				
Load $R_L$	50			$\Omega$	
Output level @ +25°C	+10	+12	-60	dBm	@ $V_{Gate} > +3.5V$
				dBm	@ $V_{Gate} < +1.5V$
Sub-Harmonics			-30	dBc	Multiples of 103 MHz
Harmonics			-40	dBc	
<b>Gate Function</b>					
Low level input voltage $V_{Gate}$		0	1.5	V	
High level input voltage $V_{Gate}$	3.5	5.0	5.5	V	
Input resistance		10		k $\Omega$	
Input capacitance			10	pF	
Turn on time			30	ns	
Turn off time			30	ns	
<b>Supply voltage <math>V_S</math></b>	11.4	12.0	12.6	V	
<b>Current consumption</b>		42	50	mA	@ $V_{Gate} > +3.5V$
		7	15	mA	@ $V_{Gate} < +1.5V$
<b>Operable temperature range</b>	-55		+85	°C	
<b>Storage temperature range</b>	-55		+125	°C	
<b>Enclosure (see drawing) (LxWxH)</b>	54x40x19 max.			mm	h = 2.0 mm
<b>Weight</b>			60	g	
<b>Packing</b>	Palette				
<b>Reliability (Note 2)</b>	633 fit / MTBF= 180 years				Operating @ +70°C
	< 10 fit				Storage @ 25°C

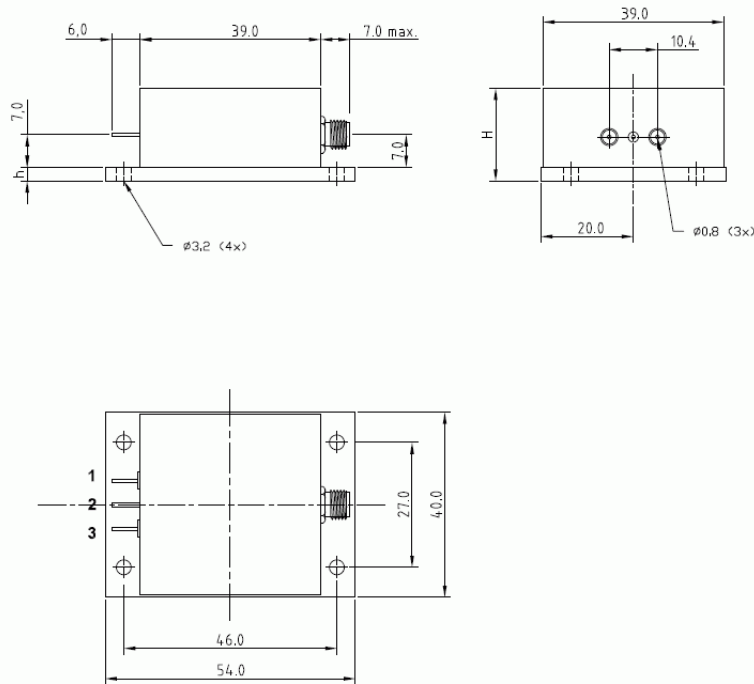
**Notes:**

1. Terminology and test conditions are according to IEC standard IEC60679-1, unless otherwise stated
2. Calculated in accordance with IEC 61709

**Ordering Code:**

Model (Specification)	Revision	Frequency [MHz]
AXMW1030GYT-01	Rev.3	1030.000

**Enclosure drawing**



**Pin connections**

Pin#	Symbol	Function
1	GATE	Gating Input
2	GND	Ground
3	$V_S$	Supply Voltage
SMA	RF OUT	RF Output

**Environmental conditions**

Test	IEC 60068 Part ...	IEC 60679-1 clause ...	Test conditions
Sealing tests (if applicable)	2-17	4.6.2	Gross leak: Test Qc
Solderability Resistance to soldering heat	2-20 2-58	4.6.3	Test Ta (235 ± 5)°C Method 1 Test Tb Method 1A, 5s
Shock*	2-27	4.6.8	Test Ea, 3 x per 6 axes 50G, 11 ms half-sine pulse
Vibration, sinusoidal*	2-6	4.6.7	Test Fc, 30 min per axes, 10 Hz - 55 Hz 0,75mm; 55 Hz - 2 kHz, 10g
Endurance tests - ageing - extended aging		4.7.1 4.7.2	30 days @ 85°C, OCXO @25°C 1000h, 2000h, 8000h @85°C

\*Endurance test

**Revision History**

Rev.	Drawing	Date [dd.mm.yyyy]	Remarks	Author	Checked
1	D0	03.12.2007	First issue	BN	BN
2	D0	13.12.2010	Crystal frequency & min. supply voltage changed, editorial changes	BN	BN
3	D0	14.12.2010	Reliability figures added	BN	BN
3	D1	29.01.2011	Package height H and thickness of base plate (h) changed: PCN11012901	BN	BN
3	D2	01.10.2012	Minor editorial changes	BN	BN
3	D3	08.07.2014	Editorial changes	HH	HH